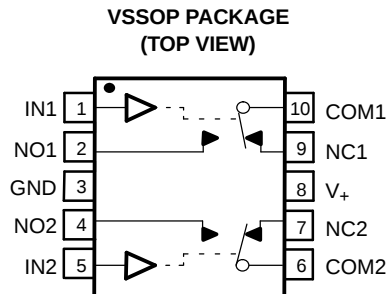


FEATURES

- Specified Make-Before-Break Switching
- Low ON-State Resistance ($1\ \Omega$)
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data Acquisition Systems
- Communication Circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Terminals and Peripherals



DESCRIPTION

The TS5A23160 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and an excellent channel-to-channel ON-state resistance matching. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

FUNCTION TABLE

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TS5A23160
0.9-Ω DUAL SPDT ANALOG SWITCH
5-V/3.3-V 2-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER

SCDS210A – AUGUST 2005 – REVISED APRIL 2006

SUMMARY OF CHARACTERISTICS⁽¹⁾

Configuration	Dual 2:1 Multiplexer/ Demultiplexer (2 × SPDT)
Number of channels	2
ON-state resistance (r_{on})	0.9 Ω
ON-state resistance match (Δr_{on})	0.1 Ω
ON-state resistance flatness ($r_{on(Flat)}$)	0.15 Ω
Turn-on/turn-off time (t_{ON}/t_{OFF})	2.5 ns/6 ns
Make-before-break time (t_{MBB})	5.5 ns
Charge injection (Q_C)	1 pC
Bandwidth (BW)	95 MHz
OFF isolation (O_{ISO})	–64 dB at 1 MHz
Crosstalk (X_{TALK})	–64 dB at 1 MHz
Total harmonic distortion (THD)	0.004%
Leakage current ($I_{NC(OFF)}$)	±20 nA
Power-supply current (I_+)	0.1 μA
Package option	10-pin VSSOP

(1) $V_+ = 5\text{ V}$, $T_A = 25^\circ\text{C}$

ORDERING INFORMATION

T_A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	VSSOP – DGS (MSOP)	Tape and reel	TS5A23160DGSR	PREVIEW

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Absolute Maximum Ratings⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾		–0.5	6.5	V
V _{NC} V _{NO} V _{COM}	Analog voltage range ⁽³⁾⁽⁴⁾⁽⁵⁾		–0.5	V ₊ + 0.5	V
I _K	Analog port diode current	V _{NC} , V _{NO} , V _{COM} < 0 or V _{NC} , V _{NO} , V _{COM} > V ₊	–50	50	mA
I _{NC} I _{NO} I _{COM}	On-state switch current	V _{NC} , V _{NO} , V _{COM} = 0 to V ₊	–200	200	mA
	On-state peak switch current ⁽⁶⁾		–400	400	
V _I	Digital input voltage range ⁽³⁾⁽⁴⁾		–0.5	6.5	V
I _{IK}	Digital input clamp current	V _I < 0	–50		mA
I ₊	Continuous current through V ₊			100	mA
I _{GND}	Continuous current through GND		–100	100	mA
θ _{JA}	Package thermal impedance ⁽⁷⁾			165	°C/W
T _{stg}	Storage temperature range		–65	150	°C

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration < 10% duty cycle
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

Electrical Characteristics for 5-V Supply⁽¹⁾
 $V_+ = 4.5 \text{ V to } 5.5 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = −100 mA,	Switch ON, See Figure 14	25°C	4.5 V	0.8		1.1	Ω
				Full		1.5			
ON-state resistance	r _{on}	V _{NO} or V _{NC} = 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 14	25°C	4.5 V	0.7		0.9	Ω
				Full		1.1			
ON-state resistance match between channels	Δr _{on}	V _{NO} or V _{NC} = 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 14	25°C	4.5 V	0.05		0.1	Ω
				Full		0.1			
ON-state resistance flatness	r _{on(flat)}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = −100 mA, V _{NO} or V _{NC} = 1 V, 1.5 V, 2.5 V, I _{COM} = −100 mA,	Switch ON, See Figure 14 Switch ON, See Figure 14	25°C	4.5 V	0.15			Ω
				25°C		0.1		0.25	
				Full		0.25			
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NC} or V _{NO} = 1 V, V _{COM} = 4.5 V, or V _{NC} or V _{NO} = 4.5 V, V _{COM} = 1 V,	Switch OFF, See Figure 15	25°C	5.5 V	−20	2	20	nA
				Full		−150		150	
	I _{NC(PWROFF)} , I _{NO(PWROFF)}	V _{NC} or V _{NO} = 0 to 5.5 V, V _{COM} = 5.5 V to 0,	Switch OFF, See Figure 15	25°C	0 V	−1		1	μA
				Full		−20		20	
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V _{NC} or V _{NO} = 1 V, V _{COM} = Open, V _{NC} or V _{NO} = 4.5 V, V _{COM} = Open,	Switch ON, See Figure 16	25°C	5.5 V	−20		20	nA
				Full		−150		150	
COM OFF leakage current	I _{COM(PWROFF)}	V _{NC} or V _{NO} = 0 to 5.5 V, V _{COM} = 5.5 V to 0,	Switch OFF, See Figure 15	25°C	0 V	−1	0.1	1	μA
				Full		−20		20	
COM ON leakage current	I _{COM(ON)}	V _{NC} or V _{NO} = Open, V _{COM} = 1 V, V _{NC} or V _{NO} = Open, V _{COM} = 4.5 V,	Switch ON, See Figure 16	25°C	5.5 V	−20	2	20	nA
				Full		−150		150	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 5-V Supply (continued)

$V_+ = 4.5 \text{ V to } 5.5 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Digital Control Inputs (IN1, IN2) ⁽²⁾									
Input logic high	V _{IH}			Full		2.4		5.5	V
Input logic low	V _{IL}			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	5.5 V	−2		2	nA
				Full		−1		1	μA
Dynamic									
Turn-on time	t _{ON}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18		25°C	5 V	1	2.5	5.5	ns
				Full	4.5 V to 5.5 V	0.5		6.5	
Turn-off time	t _{OFF}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18		25°C	5 V	2	6	10	ns
				Full	4.5 V to 5.5 V	0.5		13.5	
Make-before break time	t _{MBB}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 19		25°C	5 V		5.5		ns
				Full	4.5 V to 5.5 V	2		9.5	
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF, See Figure 23		25°C	5 V		1		pC
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF, See Figure 17		25°C	5 V		18		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V _{NC} or V _{NO} = V ₊ or GND, Switch ON, See Figure 17		25°C	5 V		55		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON, See Figure 17		25°C	5 V		55		pF
Digital input capacitance	C _I	V _I = V ₊ or GND, See Figure 17		25°C	5 V		2		pF
Bandwidth	BW	R _L = 50 Ω, Switch ON, See Figure 20		25°C	5 V		95		MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, f = 1 MHz, Switch OFF, See Figure 21		25°C	5 V		−64		dB
Crosstalk	X _{TALK}	R _L = 50 Ω, f = 1 MHz, Switch ON, See Figure 22		25°C	5 V		−64		dB
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 50 pF, f = 20 Hz to 20 kHz, See Figure 24		25°C	5 V		0.004		%
Supply									
Positive supply current	I ₊	V _I = V ₊ or GND, Switch ON or OFF		25°C	5.5 V		10		nA
				Full			0.5		μA

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics for 3.3-V Supply⁽¹⁾V₊ = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch								
Analog signal range	V _{COM} , V _{NO} , V _{NC}				0		V ₊	V
Peak ON resistance	r _{peak}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = –100 mA, Switch ON, See Figure 14	25°C Full	3 V		1.3 2	1.6	Ω
ON-state resistance	r _{on}	V _{NO} or V _{NC} = 2 V, I _{COM} = –100 mA, Switch ON, See Figure 14	25°C Full	3 V		1.2 1.7	1.5	Ω
ON-state resistance match between channels	Δr _{on}	V _{NO} or V _{NC} = 2 V, 0.8 V, I _{COM} = –100 mA, Switch ON, See Figure 14	25°C Full	3 V		0.01 0.15	0.15	Ω
ON-state resistance flatness	r _{on(flat)}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = –100 mA, Switch ON, See Figure 14	25°C Full	3 V		0.2 0.15 0.3		Ω
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NC} or V _{NO} = 1 V, V _{COM} = 3 V, or V _{NC} or V _{NO} = 3 V, V _{COM} = 1 V, Switch OFF, See Figure 15	25°C Full	3.6 V	–20 –50	2	20 50	nA
		V _{NC} or V _{NO} = 0 to 3.6 V, V _{COM} = 3.6 V to 0, Switch OFF, See Figure 15	25°C Full	0 V	–1 –15	0.2	1 15	μA
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V _{NC} or V _{NO} = 1 V, V _{COM} = Open, or V _{NC} or V _{NO} = 3 V, V _{COM} = Open, Switch ON, See Figure 16	25°C Full	3.6 V	–20 –20	2	20 20	nA
COM OFF leakage current	I _{COM(PWROFF)}	V _{NC} or V _{NO} = 3.6 V to 0, V _{COM} = 0 to 3.6 V, Switch OFF, See Figure 15	25°C Full	0 V	–1 –15	0.2	1 15	μA
COM ON leakage current	I _{COM(ON)}	V _{NC} or V _{NO} = Open, V _{COM} = 1 V, V _{NC} or V _{NO} = Open, V _{COM} = 3 V, Switch ON, See Figure 16	25°C Full	3.6 V	–20 –20	2	20 20	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 3.3-V Supply (continued)

$V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Digital Control Inputs (IN1, IN2) ⁽²⁾									
Input logic high	V _{IH}			Full		2		5.5	V
Input logic low	V _{IL}			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0	25°C	3.6 V	−2		2	nA	
			Full		−20		20		
Dynamic									
Turn-on time	t _{ON}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	3.3 V	1.5	3.5	6.5	ns	
			Full	3 V to 3.6 V	0.5		8		
Turn-off time	t _{OFF}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	3.3 V	2.5	7	11.5	ns	
			Full	3 V to 3.6 V	1		14.5		
Make-before break time	t _{MBB}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 19	25°C	3.3 V		5.5		ns	
			Full	3 V to 3.6 V	2		9.5		
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF, See Figure 23	25°C	3.3 V		3		pC	
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF, See Figure 17	25°C	3.3 V		18		pF	
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V _{NC} or V _{NO} = V ₊ or GND, Switch ON, See Figure 17	25°C	3.3 V		56		pF	
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON, See Figure 17	25°C	3.3 V		56		pF	
Digital input capacitance	C _I	V _I = V ₊ or GND, See Figure 17	25°C	3.3 V		2		pF	
Bandwidth	BW	R _L = 50 Ω, Switch ON, See Figure 20	25°C	3.3 V		95		MHz	
OFF isolation	O _{ISO}	R _L = 50 Ω, f = 1 MHz, Switch OFF, See Figure 21	25°C	3.3 V		−64		dB	
Crosstalk	X _{TALK}	R _L = 50 Ω, f = 1 MHz, Switch ON, See Figure 22	25°C	3.3 V		−64		dB	
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 50 pF, f = 20 Hz to 20 kHz, See Figure 24	25°C	3.3 V		0.01		%	
Supply									
Positive supply current	I ₊	V _I = V ₊ or GND, Switch ON or OFF	25°C	3.6 V		10		nA	
			Full			100			

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics for 2.5-V Supply⁽¹⁾
 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch								
Analog signal range	V_{COM}, V_{NO}, V_{NC}				0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 14	25°C Full	2.3 V		1.8	2.5 2.7	Ω
ON-state resistance	r_{on}	$V_{NO} \text{ or } V_{NC} = 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 14	25°C Full	2.3 V		1.5	2 2.4	Ω
ON-state resistance match between channels	Δr_{on}	$V_{NO} \text{ or } V_{NC} = 1.8 \text{ V}$, 0.8 V , $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 14	25°C Full	2.3 V		0.15	0.2 0.2	Ω
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$, $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 14	25°C	2.3 V		0.6		Ω
		$V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}$, 1.8 V , $I_{COM} = -8 \text{ mA}$, Switch ON, See Figure 14	25°C			0.6	1	
			Full				1	
NC, NO OFF leakage current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_{NC} \text{ or } V_{NO} = 0.5 \text{ V}$, $V_{COM} = 2.3 \text{ V}$, or $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V}$, $V_{COM} = 0.5 \text{ V}$, Switch OFF, See Figure 15	25°C	2.7 V	-20	2	20	μA
			Full		-50		50	
	$I_{NC(PWROFF)}, I_{NO(PWROFF)}$	$V_{NC} \text{ or } V_{NO} = 0 \text{ to } 2.7 \text{ V}$, $V_{COM} = 2.7 \text{ V to } 0$, Switch OFF, See Figure 15	25°C	0 V	-1	0.1	1	μA
			Full		-10		10	
NC, NO ON leakage current	$I_{NC(ON)}, I_{NO(ON)}$	$V_{NC} \text{ or } V_{NO} = 0.5 \text{ V}$, $V_{COM} = \text{Open}$, or $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V}$, $V_{COM} = \text{Open}$, Switch ON, See Figure 16	25°C	2.7 V	-20	2	20	nA
			Full		-20		20	
COM OFF leakage current	$I_{COM(PWROFF)}$	$V_{NC} \text{ or } V_{NO} = 2.7 \text{ V to } 0$, $V_{COM} = 0 \text{ to } 2.7 \text{ V}$, Switch OFF, See Figure 15	25°C	0 V	-1	0.1	1	nA
			Full		-10		10	
COM ON leakage current	$I_{COM(ON)}$	$V_{NC} \text{ or } V_{NO} = \text{Open}$, $V_{COM} = 0.5 \text{ V}$, $V_{NC} \text{ or } V_{NO} = \text{Open}$, $V_{COM} = 2.3 \text{ V}$, Switch ON, See Figure 16	25°C	2.7 V	-20	2	20	nA
			Full		-20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 2.5-V Supply (continued)

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Digital Control Inputs (IN1, IN2) ⁽²⁾									
Input logic high	V _{IH}			Full		1.8		5.5	V
Input logic low	V _{IL}			Full		0		0.6	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0	25°C	2.7 V		−2		2	nA
			Full			−20		20	
Dynamic									
Turn-on time	t _{ON}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	2.5 V	2	4.5	8.5	ns	
			Full	2.3 V to 2.7 V	1		10.5		
Turn-off time	t _{OFF}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	2.5 V	3.5	8.5	13.5	ns	
			Full	2.3 V to 2.7 V	1.5		16.5		
Make-before break time	t _{MBB}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 19	25°C	2.5 V		6		ns	
			Full	2.3 V to 2.7 V	8.5		10		
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF, See Figure 23	25°C	2.5 V		4.5		pC	
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF, See Figure 17	25°C	2.5 V		18.5		pF	
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V _{NC} or V _{NO} = V ₊ or GND, Switch ON, See Figure 17	25°C	2.5 V		56.5		pF	
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON, See Figure 17	25°C	2.5 V		56.5		pF	
Digital input capacitance	C _I	V _I = V ₊ or GND, See Figure 17	25°C	2.5 V		2		pF	
Bandwidth	BW	R _L = 50 Ω, Switch ON, See Figure 20	25°C	2.5 V		100		MHz	
OFF isolation	O _{ISO}	R _L = 50 Ω, f = 1 MHz, Switch OFF, See Figure 21	25°C	2.5 V		−64		dB	
Crosstalk	X _{TALK}	R _L = 50 Ω, f = 1 MHz, Switch ON, See Figure 22	25°C	2.5 V		−64		dB	
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 50 pF, f = 20 Hz to 20 kHz, See Figure 24	25°C	2.5 V		0.020		%	
Supply									
Positive supply current	I ₊	V _I = V ₊ or GND, Switch ON or OFF	25°C	2.7 V		10		nA	
			Full			50			

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TS5A23160
0.9-Ω DUAL SPDT ANALOG SWITCH
5-V/3.3-V 2-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER

SCDS210A – AUGUST 2005 – REVISED APRIL 2006

Electrical Characteristics for 1.8-V Supply⁽¹⁾

$V_+ = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = −2 mA,	Switch ON, See Figure 14	25°C	1.65 V	5		30	Ω
				Full					
ON-state resistance	r _{on}	V _{NO} or V _{NC} = 1.5 V, I _{COM} = −2 mA,	Switch ON, See Figure 14	25°C	1.65 V	2		2.5	Ω
				Full		3.5			
ON-state resistance match between channels	Δr _{on}	V _{NO} or V _{NC} = 1.5 V, I _{COM} = −8 V mA,	Switch ON, See Figure 14	25°C	1.65 V	0.15		0.4	Ω
				Full		0.4			
ON-state resistance flatness	r _{on(flat)}	0 ≤ (V _{NO} or V _{NC}) ≤ V ₊ , I _{COM} = −2 mA, V _{NO} or V _{NC} = 0.8 V, 1.8 V, I _{COM} = −8 mA,	Switch ON, See Figure 14 Switch ON, See Figure 14	25°C	1.65 V	5		1	Ω
				25°C		4.5			
				Full					
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NC} or V _{NO} = 0.3 V, V _{COM} = 1.65 V, or V _{NC} or V _{NO} = 1.65 V, V _{COM} = 0.3 V,	Switch OFF, See Figure 15	25°C	1.95 V	−20	2	20	nA
				Full		−50		50	
	I _{NC(PWROFF)} , I _{NO(PWROFF)}	V _{NC} or V _{NO} = 0 to 1.95 V, V _{COM} = 1.95 V to 0,	Switch OFF, See Figure 15	25°C	0 V	−1	0.1	1	μA
				Full		−5		5	
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V _{NC} or V _{NO} = 0.3 V, V _{COM} = Open, or V _{NC} or V _{NO} = 1.65 V, V _{COM} = Open,	Switch ON, See Figure 16	25°C	1.95 V	−20	2	20	nA
				Full		−20		20	
COM OFF leakage current	I _{COM(PWROFF)}	V _{NC} or V _{NO} = 1.95 V to 0, V _{COM} = 0 to 1.95 V,	Switch OFF, See Figure 15	25°C	0 V	−1	0.1	1	μA
				Full		−5		5	
COM ON leakage current	I _{COM(ON)}	V _{NC} or V _{NO} = Open, V _{COM} = 0.3 V, V _{NC} or V _{NO} = Open, V _{COM} = 1.65 V,	Switch ON, See Figure 16	25°C	1.95 V	−20	2	20	nA
				Full		−20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 1.8-V Supply (continued)

$V_+ = 1.65\text{ V}$ to 1.95 V , $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Digital Control Inputs (IN1, IN2) ⁽²⁾									
Input logic high	V _{IH}			Full		1.5		5.5	V
Input logic low	V _{IL}			Full		0		0.6	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0	25°C	1.95 V	−2		2	nA	
			Full		−20		20		
Dynamic									
Turn-on time	t _{ON}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	1.8 V	2.5	10	14.5	ns	
			Full	1.65 V to 1.95 V	1		17		
Turn-off time	t _{OFF}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 18	25°C	1.8 V	6.5	12.5	21.5	ns	
			Full	1.65 V to 1.95 V	2		24		
Make-before break time	t _{MBB}	V _{COM} = V ₊ , R _L = 50 Ω, C _L = 35 pF, See Figure 19	25°C	1.8 V		6.5		ns	
			Full	1.65 V to 1.95 V	2.5		14		
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF, See Figure 23	25°C	1.8 V		5.5		pC	
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF, See Figure 17	25°C	1.8 V		18.5		pF	
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V _{NC} or V _{NO} = V ₊ or GND, Switch ON, See Figure 17	25°C	1.8 V		56.5		pF	
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON, See Figure 17	25°C	1.8 V		56.5		pF	
Digital input capacitance	C _I	V _I = V ₊ or GND, See Figure 17	25°C	1.8 V		2		pF	
Bandwidth	BW	R _L = 50 Ω, Switch ON, See Figure 20	25°C	1.8 V		100		MHz	
OFF isolation	O _{ISO}	R _L = 50 Ω, f = 1 MHz, Switch OFF, See Figure 21	25°C	1.8 V		−64		dB	
Crosstalk	X _{TALK}	R _L = 50 Ω, f = 1 MHz, Switch ON, See Figure 22	25°C	1.8 V		−64		dB	
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 50 pF, f = 20 Hz to 20 kHz, See Figure 24	25°C	1.8 V		0.060		%	
Supply									
Positive supply current	I ₊	V _I = V ₊ or GND, Switch ON or OFF	25°C	1.95 V				nA	
			Full		50				

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

TYPICAL PERFORMANCE

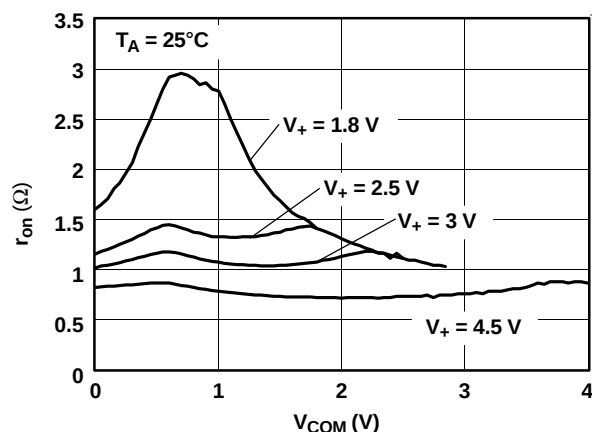
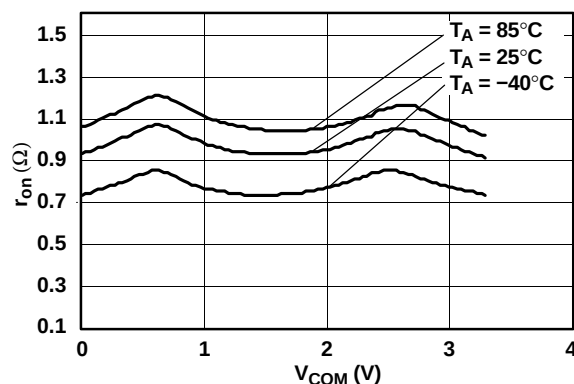
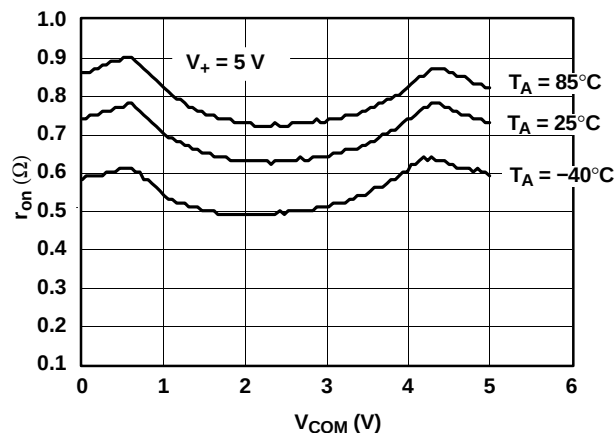
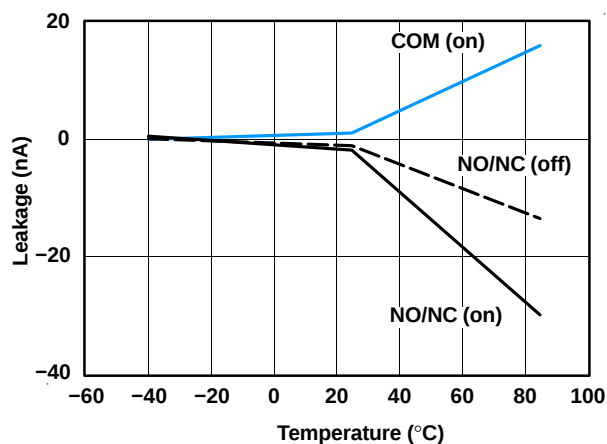
Figure 1. r_{on} vs V_{COM} Figure 2. r_{on} vs V_{COM} ($V_+ = 3.3\text{ V}$)Figure 3. r_{on} vs V_{COM} 

Figure 4. Leakage Current vs Temperature

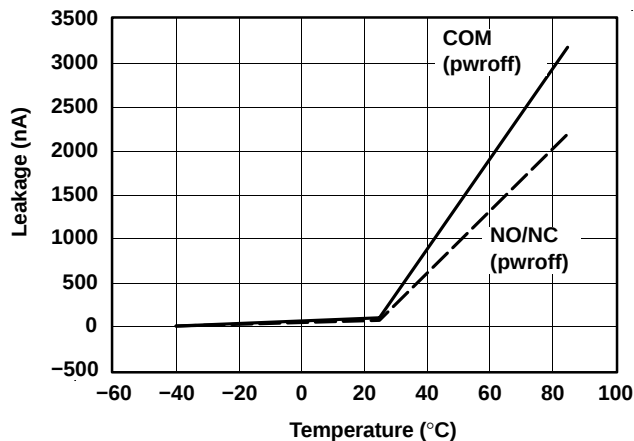
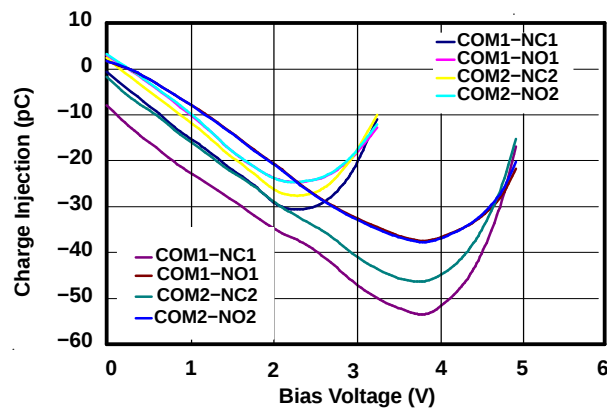


Figure 5. Leakage Current vs Temperature

Figure 6. Charge Injection (Q_C) vs V_{COM}

TYPICAL PERFORMANCE (continued)

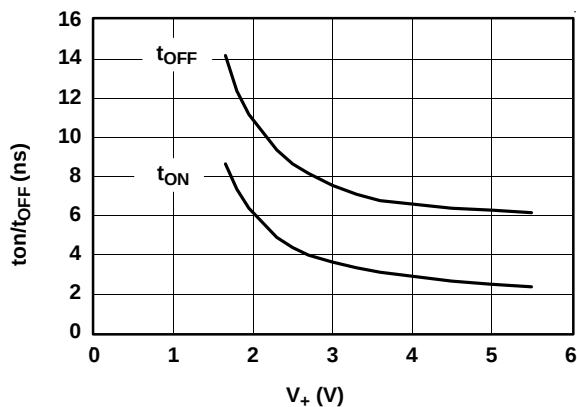


Figure 7. t_{ON} and t_{OFF} vs Supply Voltage

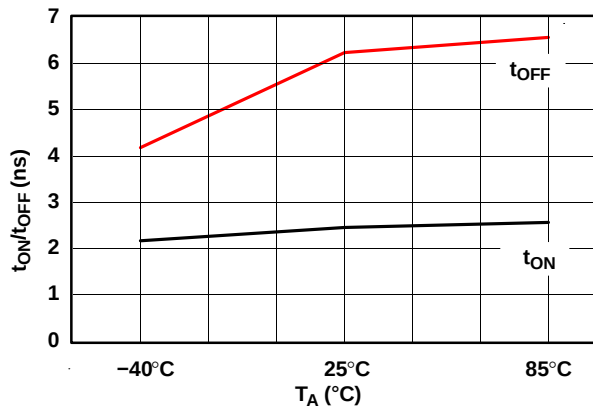


Figure 8. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

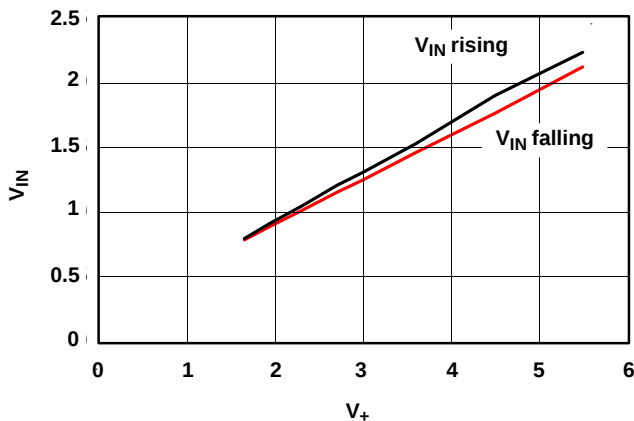


Figure 9. Logic Threshold vs V₊

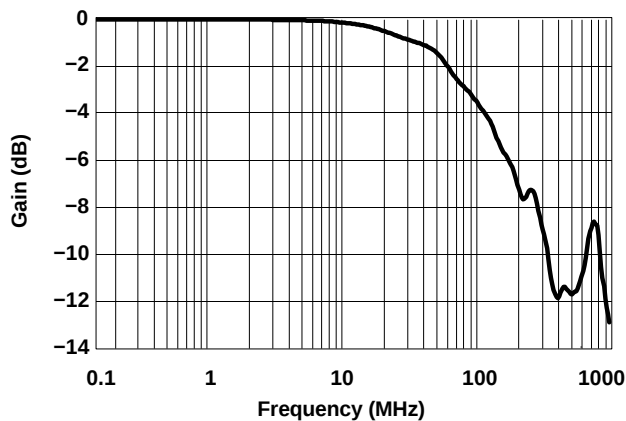


Figure 10. Bandwidth (Gain vs Frequency)
(V₊ = 5 V)

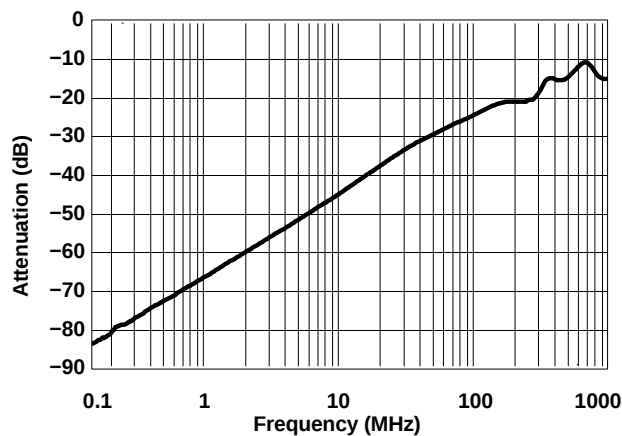


Figure 11. OFF Isolation vs Frequency

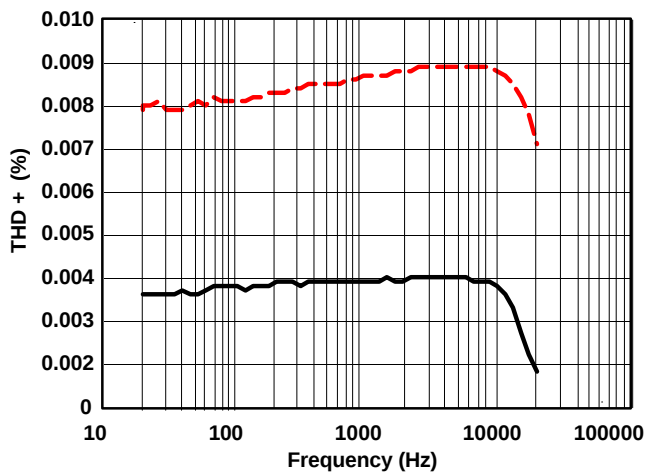


Figure 12. Total Harmonic Distortion
vs Frequency (V₊ = 5 V)

TYPICAL PERFORMANCE (continued)

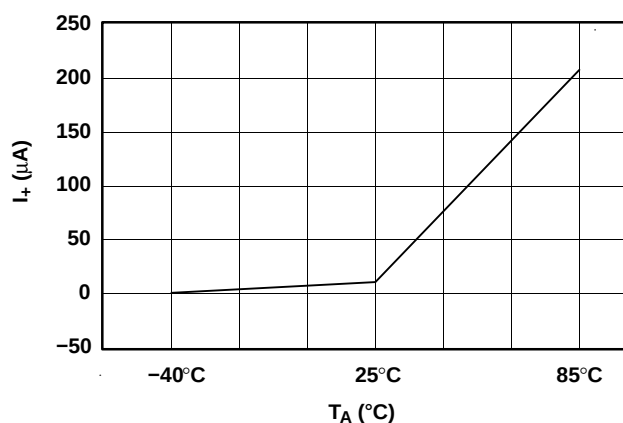


Figure 13. Power-Supply Current vs Temperature ($V_+ = 5\text{ V}$)

PIN DESCRIPTION

PIN	NAME	DESCRIPTION
1	IN1	Digital control to connect COM to NO or NC
2	NO1	Normally open
3	GND	Digital ground
4	NO2	Normally open
5	IN2	Digital control to connect COM to NO or NC
6	COM2	Common
7	NC2	Normally closed
8	V+	Power supply
9	NC1	Normally closed
10	COM1	Power supply

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V_{COM}	Voltage at COM
V_{NC}	Voltage at NC
V_{NO}	Voltage at NO
r_{on}	Resistance between COM and NC or COM and NO ports when the channel is ON
r_{peak}	Peak on-state resistance over a specified voltage range
Δr_{on}	Difference of r_{on} between channels in a specific device
$r_{on(flat)}$	Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions
$I_{NC(OFF)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst-case input and output conditions
$I_{NC(PWROFF)}$	Leakage current measured at the NC port during the power-down condition, $V_+ = 0$
$I_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state under worst-case input and output conditions
$I_{NO(PWROFF)}$	Leakage current measured at the NO port during the power-down condition, $V_+ = 0$
$I_{NC(ON)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open
$I_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
$I_{COM(PWROFF)}$	Leakage current measured at the COM port during the power-down condition, $V_+ = 0$
$I_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NC or COM to NO) in the ON state and the output (NC or NO) open
V_{IH}	Minimum input voltage for logic high for the control input (IN)
V_{IL}	Maximum input voltage for logic low for the control input (IN)
V_I	Voltage at the control input (IN)
I_{IH}, I_{IL}	Leakage current measured at the control input (IN)
t_{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning ON.
t_{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning OFF.
t_{MKB}	Make-before-break time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
Q_C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NO, or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$. C_L is the load capacitance and ΔV_{COM} is the change in analog output voltage.
$C_{NC(OFF)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF
$C_{NO(OFF)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
$C_{NC(ON)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is ON
$C_{NO(ON)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
$C_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON
C_I	Capacitance of control input (IN)
O_{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.
X_{TALK}	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I_+	Static power-supply current with the control (IN) pin at V_+ or GND

PARAMETER MEASUREMENT INFORMATION

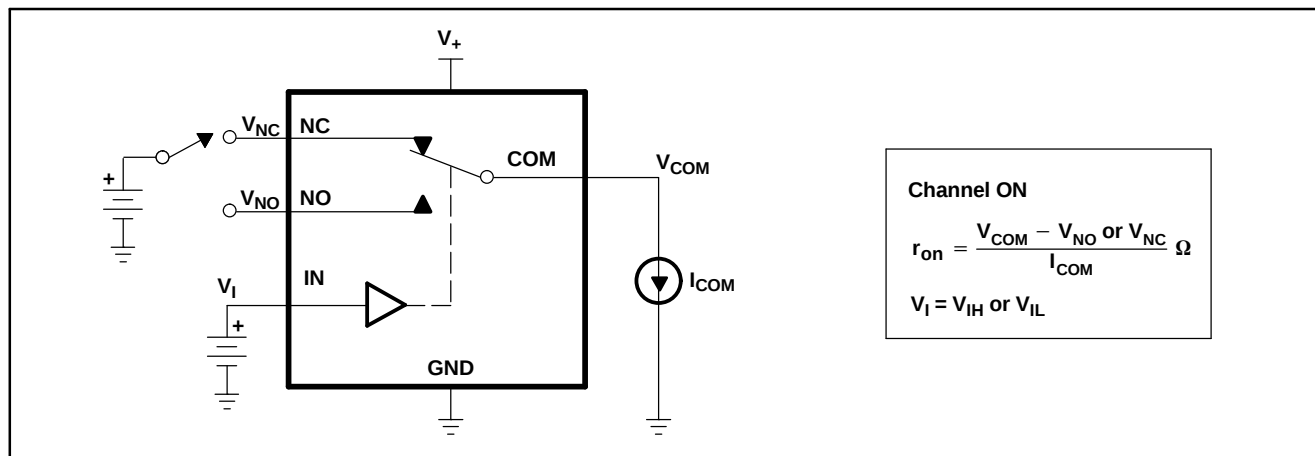


Figure 14. ON-State Resistance (r_{on})

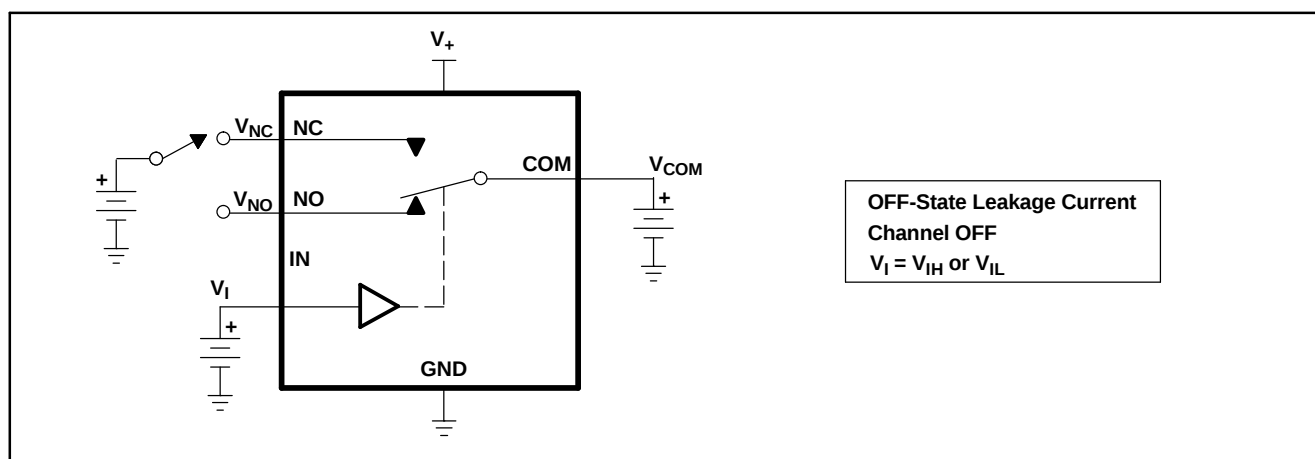


Figure 15. OFF-State Leakage Current ($I_{NC(OFF)}$, $I_{NC(PWROFF)}$, $I_{NO(OFF)}$, $I_{NO(PWROFF)}$, $I_{COM(OFF)}$, $I_{COM(PWROFF)}$)

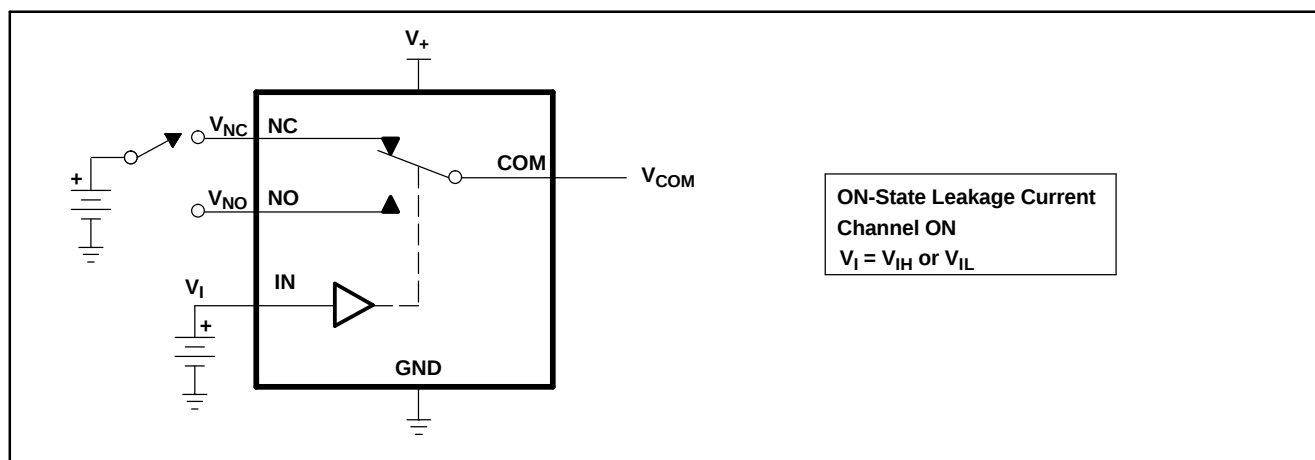


Figure 16. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)

PARAMETER MEASUREMENT INFORMATION (continued)

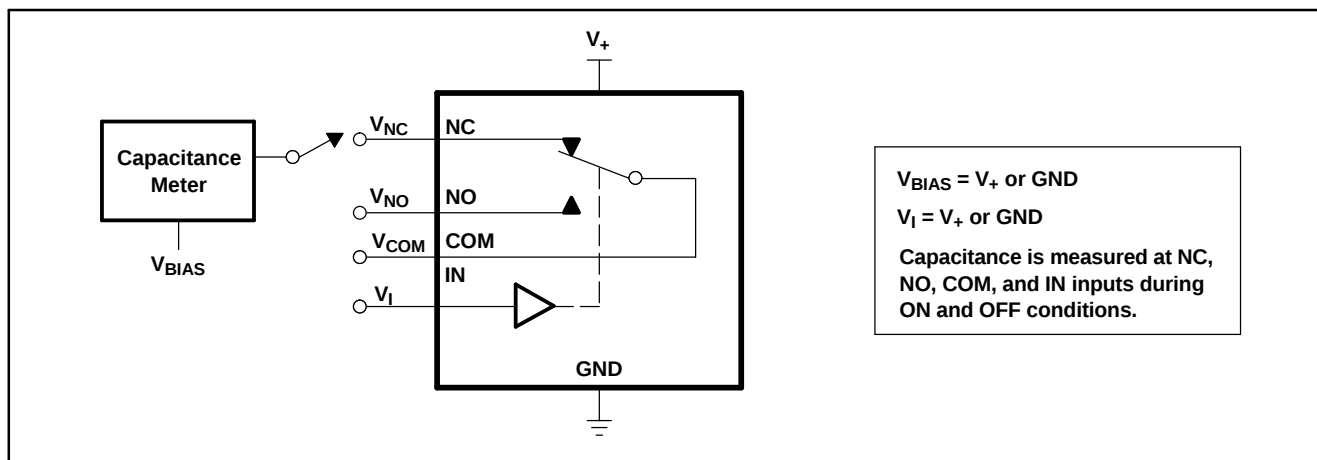
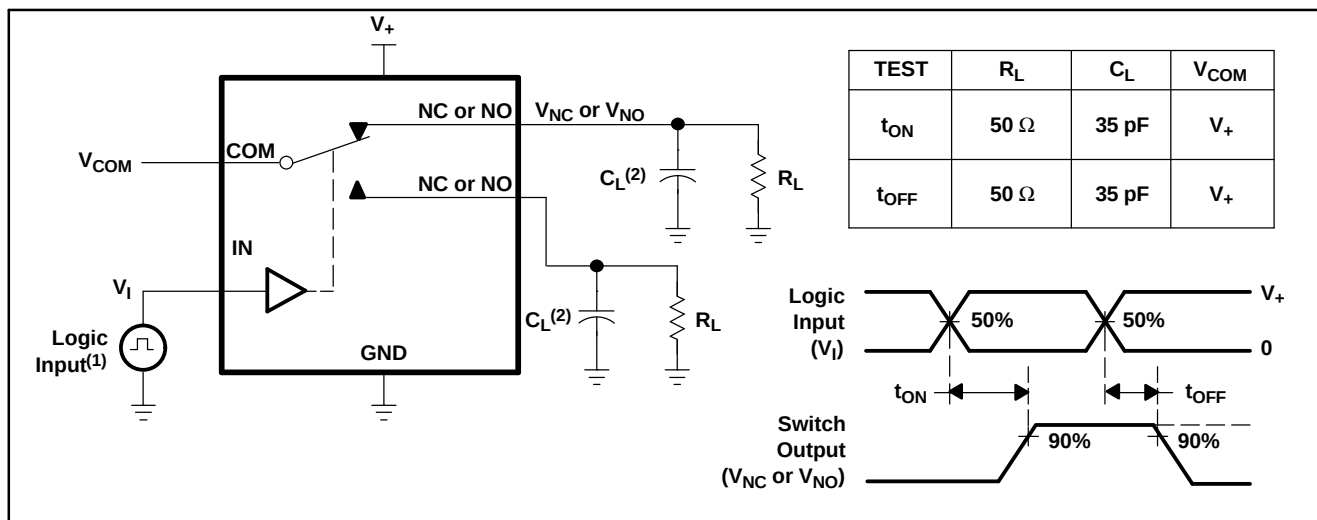


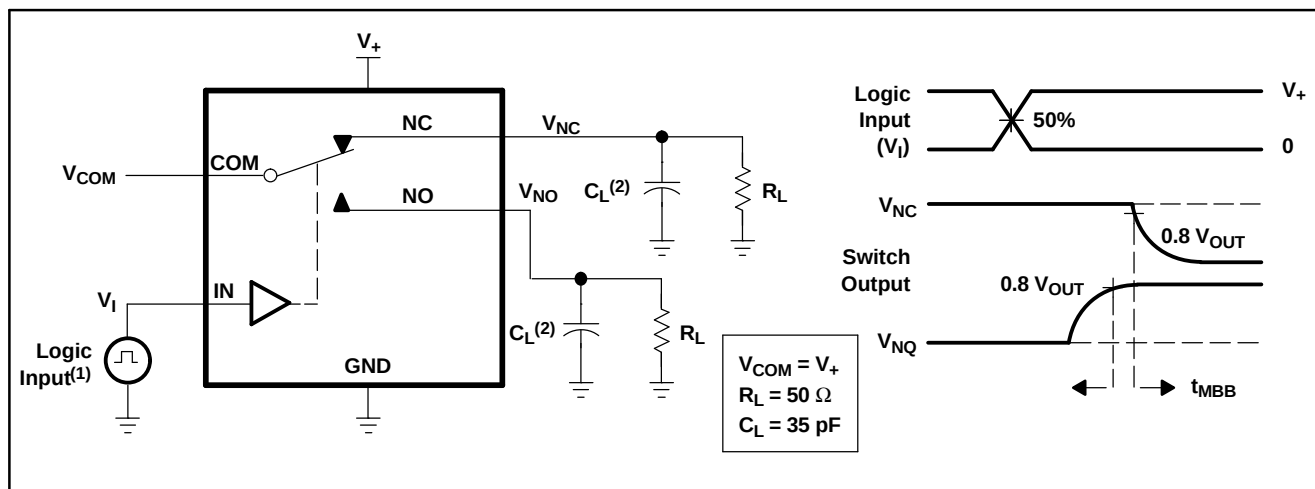
Figure 17. Capacitance (C_I , $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)



- A. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- B. C_L includes probe and jig capacitance.

Figure 18. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

PARAMETER MEASUREMENT INFORMATION (continued)



- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- C_L includes probe and jig capacitance.

Figure 19. Make-Before-Break Time (t_{MBB})

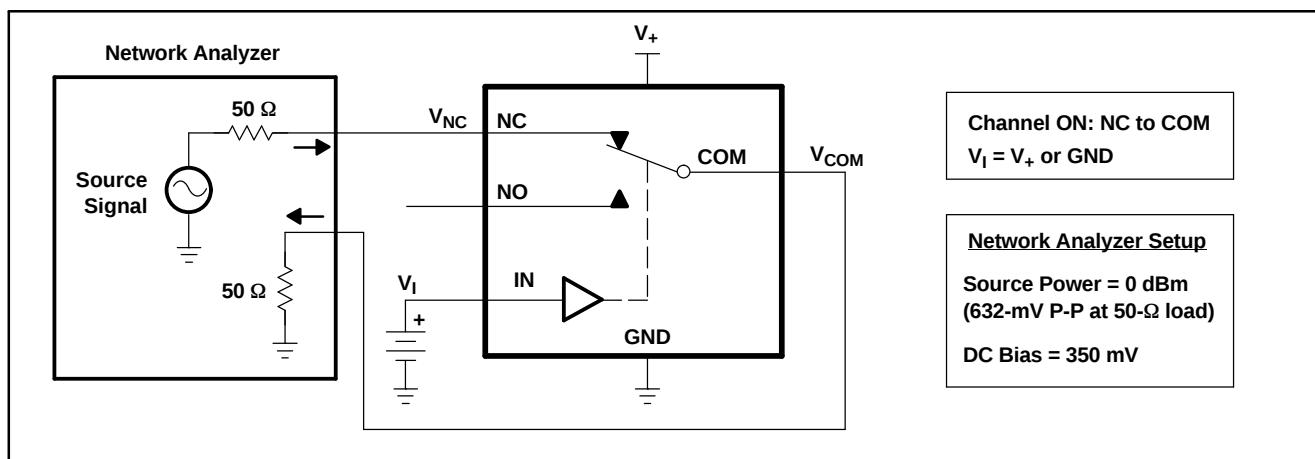


Figure 20. Bandwidth (BW)

PARAMETER MEASUREMENT INFORMATION (continued)

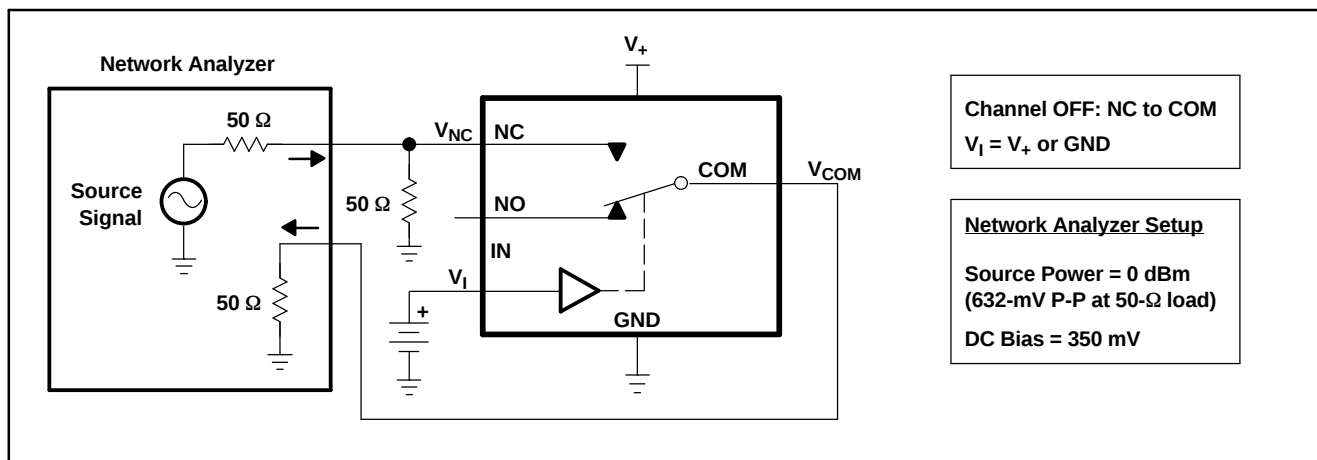
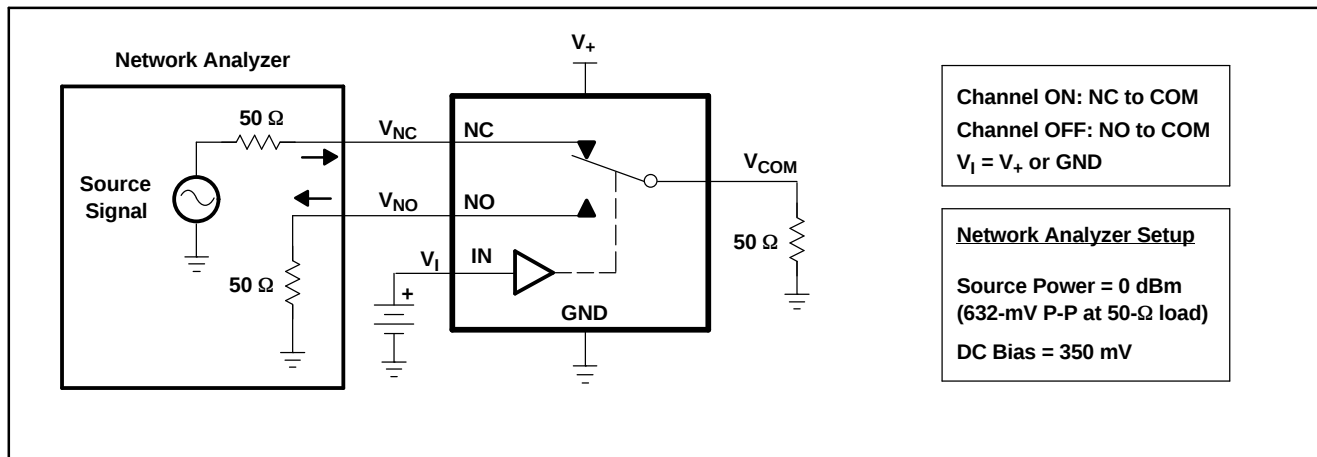


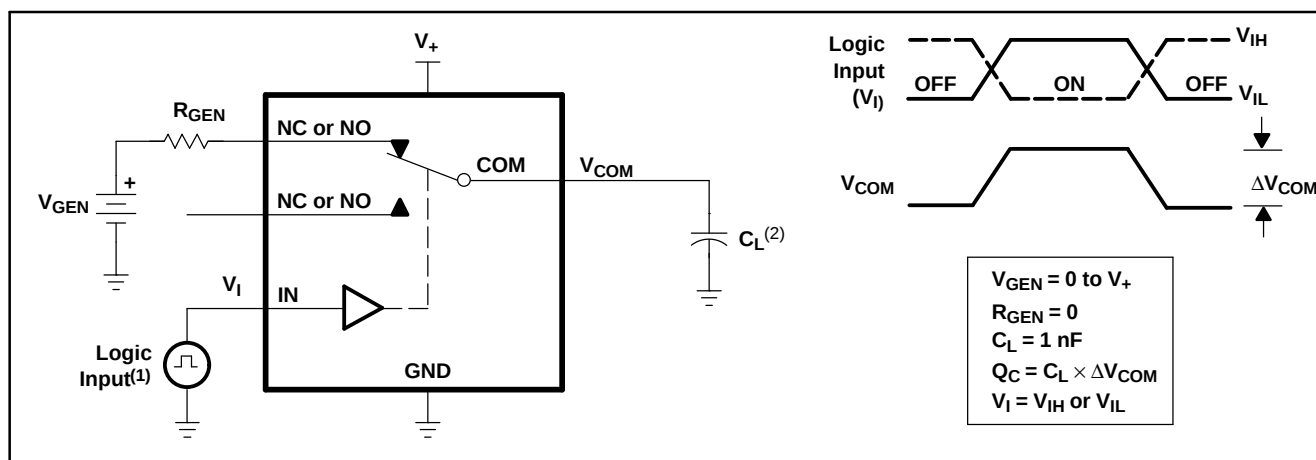
Figure 21. OFF Isolation (O_{ISO})



- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50$ Ω , $t_r < 5$ ns, $t_f < 5$ ns.
- C_L includes probe and jig capacitance.

Figure 22. Crosstalk (X_{TALK})

PARAMETER MEASUREMENT INFORMATION (continued)



A. C_L includes probe and jig capacitance.

Figure 23. Charge Injection (QC)

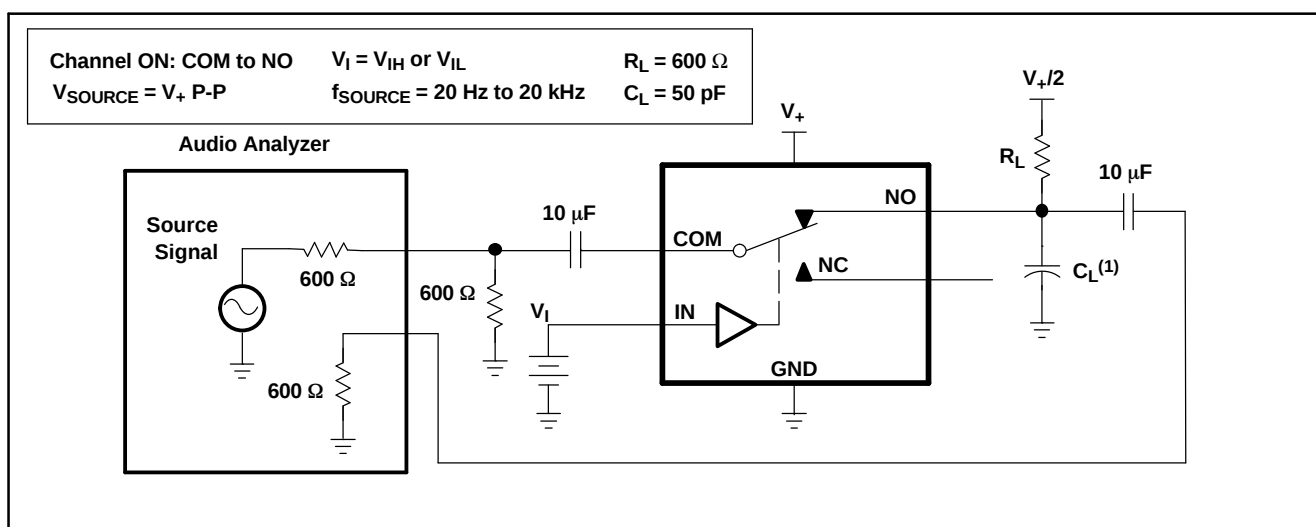


Figure 24. Total Harmonic Distortion (THD)

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS5A23160DGSR	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JLR	Samples
TS5A23160DGSRG4	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JLR	Samples
TS5A23160DGST	ACTIVE	VSSOP	DGS	10	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JLR	Samples
TS5A23160DGSTE4	ACTIVE	VSSOP	DGS	10	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JLR	Samples
TS5A23160DGSTG4	ACTIVE	VSSOP	DGS	10	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JLR	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

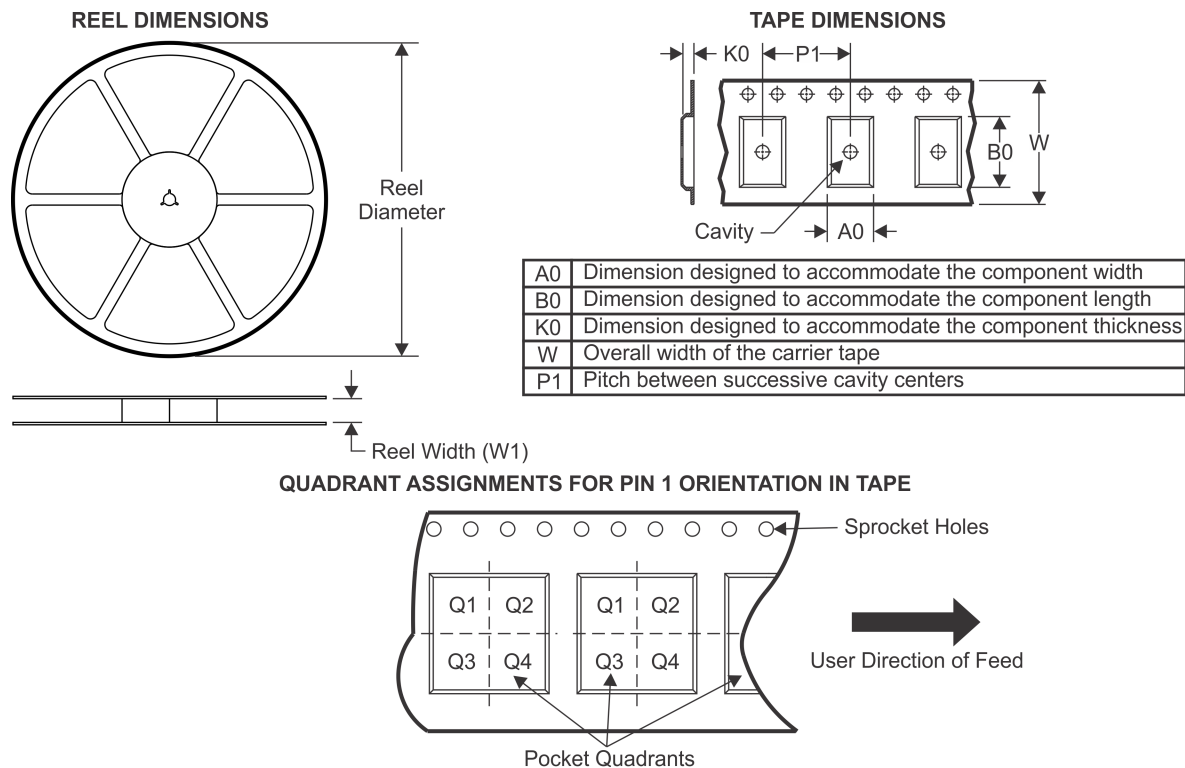
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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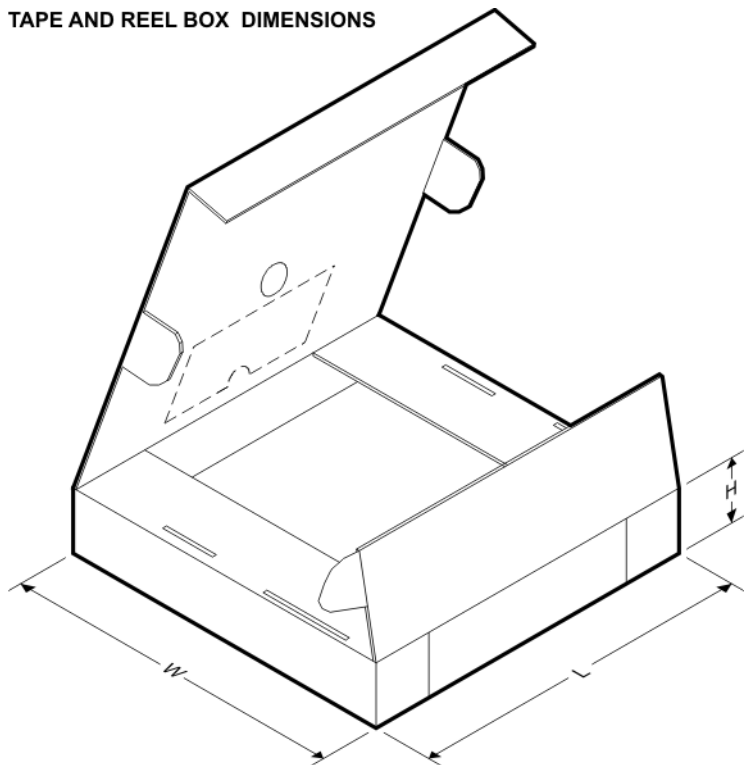
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

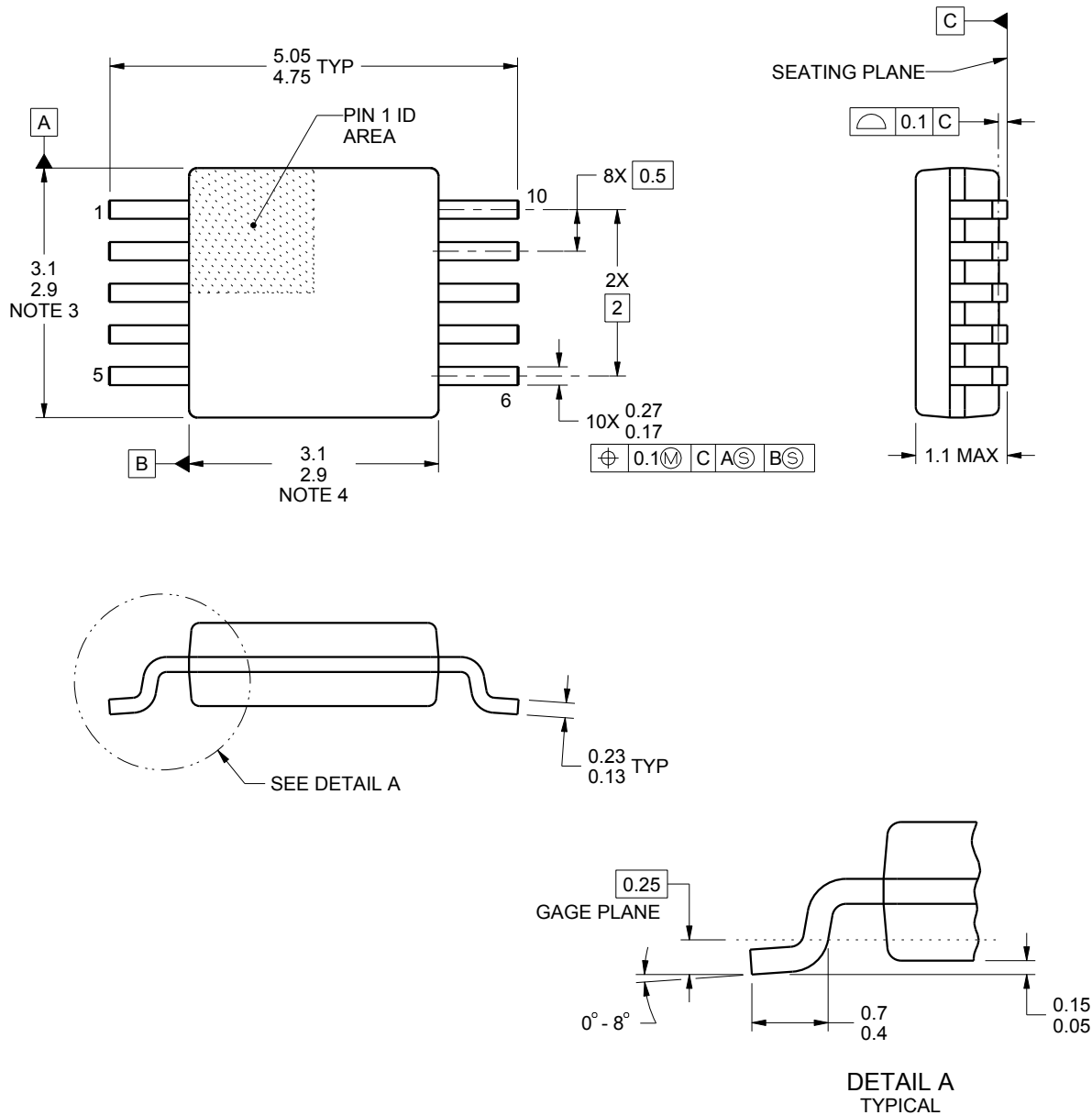
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A23160DGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TS5A23160DGST	VSSOP	DGS	10	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A23160DGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TS5A23160DGST	VSSOP	DGS	10	250	358.0	335.0	35.0



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NOTES:

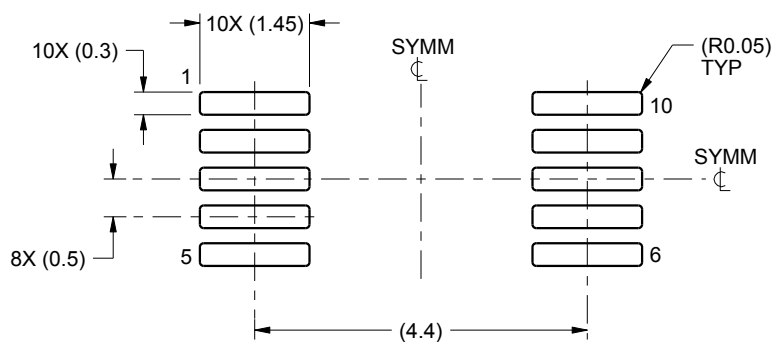
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

EXAMPLE BOARD LAYOUT

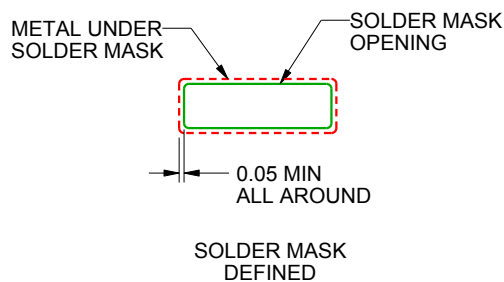
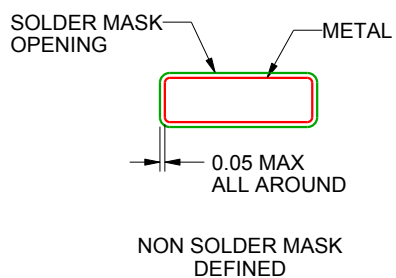
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

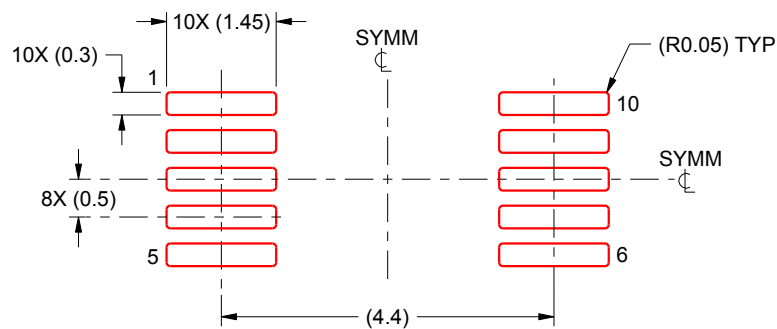
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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